Quantum-chemical simulation of the electronic structure and chemical bonding in the new 'superstoichiometric' titanium carbonitride Ti_2CN_4

Mikhail V. Ryzhkov* and Alexander L. Ivanovskii

Institute of Solid State Chemistry, Urals Branch of the Russian Academy of Sciences, 620219 Ekaterinburg, Russian Federation. Fax: +7 3432 74 4495; e-mail: ryzhkov@ihim.uran.ru

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The electronic properties and the nature of interatomic interactions in the new 'superstoichiometric' metal-like titanium carbonitride Ti_2CN_4 with the spinel structure have been predicted using the *ab initio* DFT-DV calculaions of large clusters.

Two classes of compounds provide the basis for the quest of novel ceramic and composite materials. The first class includes compounds of d metals (M) with light sp elements. Among them are cubic (B1-type) carbides and nitrides $[M(C,N)]^1$ which (i) have wide homogeneity regions [containing a variable number of vacancies in the non-metallic sublattice $M(C,N)_y$ 0.5<y<1.0] and (ii) form mutual solid solutions. The properties of solid solutions (for example, carbonitrides MC_xN_y , $x+y \le 1.0$) change non-monotonically with concentration. 1.2 It is important that atoms in these systems have an octahedral environment and the relative content of atomic components does not exceed $(C,N)/M \le 1.0$. The exception being several 'superstoichiometric' nitrides $(MN_{y>1})$ obtained as films) where the ratio N/M > 1.0 is achieved due to the presence of vacancies in the M sublattice.³

The second class comprises refractory compounds of sp nonmetals [carbides, nitrides and oxides of B, Si and Al, multicomponent phases, for instance, silicon oxynitrides (Si₂N₂O), sialons (Al_{x+y}Si_{6-x}O_xN_{8-x+y}), $etc.^4$] characterised by a tetrahedral atomic coordination.

Recently, the synthesis (at P = 15 GPa and $T \approx 2000$ K) of the new polymorphous modification of silicon nitride with the cubic structure (c-Si₃N₄) was reported.⁵ According to estimates,⁵ its cohesive properties are similar to those of the hardest modification of SiO₂ (stishovite). The new c-Si₃N₄ phase is of the

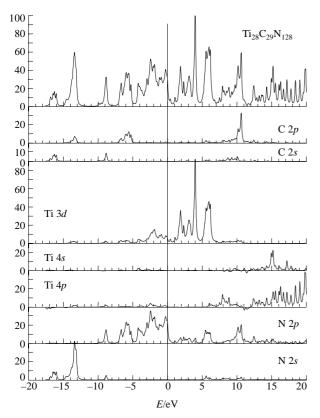


Figure 1 Total (top) and partial densities of states for the ${\rm Ti}_{28}C_{29}N_{128}$ cluster.

Table 1 Overlap populations (OP, e) of the valence orbitals of neighbouring atoms in TiN, Ti_2CN_4 and C_3N_4 (×10³, per pair of interacting centres) and effective atomic charges ($Q_{\rm ef}$, e) in TiN, Ti_2CN_4 and C_3N_4 (the charges obtained according to the Mulliken scheme are given in brackets).

OP		TiN		Ti_2CN_4		C_3N_4	
		N 2s	N 2p	N 2s	N 2p	N 2s	N 2p
Ti(Co)	3d	33	121	37	174		
	4s(2s)	-25	77	-1	73	_7	130
	4p(2p)	87	68	53	48	79	229
C^t	2s	_	_	14	205	-15	202
	2p	_	_	173	349	127	348
$Q_{\mathrm{ef}}\left[\mathrm{Ti}\left(\mathrm{C^{o}}\right)\right]$		1.43 (0.82)		1.49 (0.88)		0.57 (0.29)	
$Q_{\mathrm{ef}}\left(\mathrm{C^{t}}\right)$		_		0.55 (0.36)		0.54 (0.34)	
$Q_{\rm ef}\left({\rm N}\right)$		-1.59 (-0.83)		-0.93 (-0.53)		-0.42 (-0.23)	

spinel structural type and contains silicon atoms in octahedral $[Si^oN_6]$ and tetrahedral $[Si^tN_4]$ surroundings $(Si^o\!:\!Si^t=2\!:\!1)$.

By substituting C or Ti for silicon in c-Si₃N₄, the simulation of novel compounds, namely, the cubic carbon nitride (C_2^o CtN₄)⁶ and the 'superstoichiometric' titanium nitride (T_1^o TitN₄)⁷ was made. These hypothetical phases include 2/3 (C^o) or 1/3 (T^i) cations in an octahedral or tetrahedral environment, which are not typical (in the corresponding binary phases C_3 N₄ and TiN), *i.e.*, the proposed^{6,7} compounds are difficult to synthesise.

According to our opinion, it is more realistic to obtain a new cubic phase with the spinel structure, viz., the 'superstoichiometric' titanium carbonitride of the formal composition Ti_2CN_4 , which will be isoelectronic and isostructural with $c\text{-}Si_3N_4$ and will contain C and Ti cations in inherent to them (in binary nitrides) octahedral [Ti_0N_6] and tetrahedral [C^tN_4] coordinations. It may be suggested that, assembled of the main 'structural fragments' TiN and C_3N_4 , the 'superstoichiometric' carbonitride Ti_2CN_4 may possess an unusual combination of their most attractive properties: the plasticity of a metal-like titanium nitride^{1,2} and the hardness of a high-covalence carbon nitride.⁸

We performed a quantum-chemical simulation of the electronic structure and interatomic bonds in Ti₂CN₄ and compared them with those of the known nitrides TiN and C_3N_4 . The electronic structure was calculated in the density functional theory (DFT) approximation using the original code of the self-consistent discrete variational (DV)8 cluster method with local exchange-correlation potential.9 The basis set of numerical atomic orbitals (AO), which were the solutions of Hartree–Fock–Slater equations for isolated neutral atoms, included Ti 4p functions in addition to occupied AOs. The Diophantine integration grid with 4000 and 2000 sample points per each Ti and C(N) site, respectively, was used for the calculations of matrix elements. Ti₂CN₄ was simulated by the 185-atomic cluster $Ti_{28}C_{29}N_{128}$ (point group symmetry T_d). It is known¹⁰ that the positions of atoms in the spinel structure (space group $Fd3m-O_h^7$) are determined by two parameters a and x. Assuming that the parameters of the coordination polyhedra [Ti $^{\circ}$ N₆] and [C † N₄] for Ti $^{\circ}$ CN₄ are equal to those for TiN ($R_{\text{Ti-N}} = 2.122 \text{ Å}$) and C $_{3}$ N₄ ($R_{\text{C-N}} = 1.585 \text{ Å}$), we derived the values a = 8.098 Å and x = 0.363. To compare the electronic structure of Ti₂CN₄ and C₃N₄ obtained using a similar

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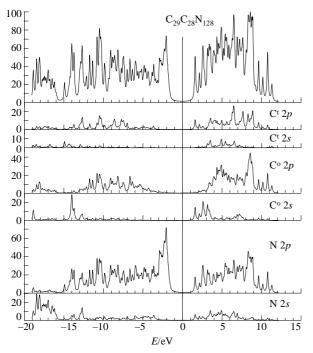


Figure 2 Total (top) and partial densities of states for the $\,C_{28}^o\,C_{29}^t\,N_{128}^{}$ cluster.

approach, we also performed DFT-DV calculations of the cluster $C_{28}^{\circ}\,C_{29}^{t}\,N_{128}$ in the $C_{3}N_{4}$ structure with bond lengths of 1.585 and 1.676 Å for C'–N and C°–N, respectively.6 Boundary conditions in the 'extended cluster' scheme 11,12 were used.

The model densities of states (MDOS) of the cluster ${\rm Ti}_{28}{\rm C}_{29}{\rm N}_{128}$ are presented in Figure 1. The total band width of bonding states is about 10 eV. It is made up of the contributions from hybrid Ti 3d–N 2p (0–5 eV), N 2p–C 2p (5–7.5 eV) and N 2p–C 2s orbitals [7.5–10 eV below the Fermi level ($E_{\rm F}$)] that form Ti–N and C–N bonds in [Ti°N $_6$] and [C¹N $_4$] polyhedra. Ti $_2$ CN $_4$ has no forbidden gap (FG) and will exhibit metal-like properties.

A comparison with DFT-DV results for the cluster ${\rm Ti}_{79}{\rm N}_{140}$ used to model ${\rm TiN}^{13}$ shows that the most essential differences in the electronic structures of ${\rm TiN}$ and ${\rm Ti}_2{\rm CN}_4$ concern the mutual arrangement of the ${\rm Ti}$ 3d and ${\rm N}$ 2p states. In the nitride, the upper edge of the ${\rm N}$ 2p band (total width of 5 eV) is 4 eV below $E_{\rm F}$ located in the region of π -like antibonding ${\rm Ti}$ 3d states. ${\rm I}^{13}$

The cubic C₃N₄ has a FG of more than 3 eV according to our calculations (1.14 eV according to ref. 7); its spectrum (Figure 2) contains a continuous N 2s,p-C 2s,p band of the total width of 17 eV. The differences in the MDOS of C^t centres in C₃N₄ and Ti_2CN_4 are attributed to the considerable broadening of $C^t 2s, 2p$ bands, their shift to lower binding energies and a decrease of C^{t} 2s,2p-N 2s hybridization in the nitride. The differences in the MDOS of C^t and C^o in C_3N_4 concern the different hybridization effects in $[C^tN_4]$ and $[C^oN_6]$ polyhedra. The orbital overlap populations (OP) of TiN, C_3N_4 and Ti_2CN_4 obtained by the same cluster DFT-DV method are listed in Table 1. It can be seen that on going from TiN to Ti₂CN₄ the OP of Ti 3d-N 2p AO, which provides the major contribution to the Ti-N bonding, increase appreciably, whereas the OP of Ti 4p–N 2s and Ti 4p–N 2p AO decrease slightly. In general, the Ti-N chemical bonding in the simulated carbonitride is not weaker than that in TiN. A comparison of the OP of C^t centres with the neighbours in Ti₂CN₄ and C₃N₄ shows that the C^LN bonds in the carbonitride are stronger due to the C^t 2p-N 2s hybridization. The fact that the octahedral coordination is less advantageous for carbon is evident from a comparison of the OP of Ct-N and Co-N in C₃N₄: all the contributions forming the Co-N bonding are on the average 1.5 times smaller than those for Ct-N.

Let us compare effective atomic charges $(Q_{\rm ef})$ in TiN, Ti₂CN₄ and C₃N₄ (Table 1), which were obtained by three-dimensional integration in the space between nuclei. ¹¹ The values of $Q_{\rm ef}$ at

Ti in TiN and Ti₂CN₄ appear to be similar, whereas the charges at nitrogen atoms in the carbonitride are only $\approx 60\%$ of the corresponding values for TiN. The fundamental difference between Ti_2CN_4 and the known B1 carbonitrides MC_xN_y $(x + y \le 1.0)$ incorporating carbon in the anionic state² is the cationic form of Ct, the effective charges of Ct in Ti₂CN₄ and C₃N₄ being very close. The charges at N in C₃N₄ are half as large as in Ti₂CN₄ and are lower than those in TiN by a factor of 4, i.e., Ti₂CN₄ is intermediate in the degree of ionicity among the binary nitrides under consideration. In conclusion, note that due to the similarity of the simulated 'superstoichiometric' titanium nitride Ti₂CN₄ and the familiar interstitial phase TiN, Ti₂CN₄ may be expected to have properties² typical of those of titanium nitride, such as nonstoichiometry in the N sublattice (Ti₂CN_{4-y}-type compositions) or the formation of multicomponent solid solutions by replacing Ti atoms by other d metals (for example, Ti_{2-x}Zr_xCN₄ and Ti_{2-x}Hf_xCN₄). The synthesis of more complicated phases, where Si or Ge partially substitute for carbon, is possible.

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